

Over-voltage Protection Thyristor

SPXXX0SC MC

ROHS

Description

DO-214AA P Series solid state protection thyristor protect telecommunications equipment such as modems, line cards, fax machines, and other CPE.

P Series devices are used to enable equipment to meet various regulatory requirements including GR 1089, ITU K.20, K.21 and K.45, IEC 60950, UL 60950, and TIA-968 (formerly known as FCC Part 68).

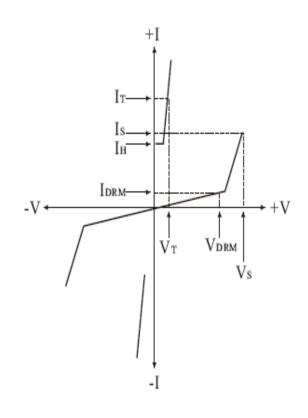


Compared to surge suppression using other technologies, P Series devices offer absolute surge protection regardless of the surge current available and the rate of applied voltage (dv/dt). P Series devices:

- Cannot be damaged by voltage
- Eliminate hysteresis and heat dissipation typically found with clamping devices
- Eliminate voltage overshoot caused by fast-rising transients
- Are non-degenerative
- Will not fatigu
- Have low capacitance, making them ideal for high-speed transmission equipment

Electrical Parameters

Parameter	Definition			
C 0	Off-state Capacitance — typical capacitance			
	measured in off state			
di/dt	Rate of Rise of Current — maximum rated value of			
	the acceptable rate of rise in current over time			
Is	${f Switching}$ ${f Current}$ — maximum current required to			
	switch to on state			
I DRM	Leakage Current — maximum peak off-state current			
	measured at VDRM			
\mathbf{I}_{H}	Holding Current — minimum current required to			
	maintain on state			
I PP	Peak Pulse Current — maximum rated peak impulse			
	current			
\mathbf{I}^{\intercal}	On-state Current — maximum rated continuous			
	on-state current			
I TSM	Peak One-cycle Surge Current — maximum rated			
	one-cycle AC current			
V S	Switching Voltage — maximum voltage prior to			
	switching to on state			
V DRM	Peak Off-state Voltage — maximum voltage that can			
	be applied while maintaining off state			
V F	On-state Forward Voltage — maximum forward			
	voltage measured at rated on-state current			
V T	On-state Voltage — maximum voltage measured at			
	rated on-state current			





Over-voltage Protection Thyristor SPXXX0SC MC **ROHS** ElectricalCharacteristics Vт Part VDRM Vs Is Ιτ Co IDRM IΗ Number* Volts Volts Volts μ Amps Amps mAmps рF mAmps SP0080SC MC 2.2 SP0300SC MC 2.2 SP0640SC MC 2. 2 SP0720SC MC 2. 2 SP0900SC MC 2.2 SP1100SC MC 2. 2 SP1300SC MC 2.2 SP1500SC MC 2. 2 2.2 SP1800SC MC SP2000SC MC 2. 2 SP2300SC MC 2.2 SP2600SC MC 2. 2 SP3100SC MC 2.2 SP3500SC MC 2.2

Notes:

• All measurements are made at an ambient temperature of 25°C. IPP applies to -40°C through +85°C temperature range.

ullet Off-state capacitance (Co) is measured at 1 MHz with a 2 V bias and is typical value.

Surge Ratings

SP4000SC MC

SP4500SC MC

SP5000SC MC

Series	I _{PP} 2x10 μs	Ipp 8x20 μs	IPP 10x160 µs	I _{PP} 10x560 μs	IPP 10x1000 μs	Itsm 60 Hz	di/dt
С	Amps	Amps	Amps	Amps	Amps	Amps	Amps/μs
	500	400	200	150	100	50	500

2. 2

2.2

2. 2

Thermal Considerations

Package DO-214AA/SMB	Symbol	Parameter	Value	Unit
	Тл	Operating Junction Temperature	-40 to +150	$^{\circ}$ C
	Ts	Storage Temperature Range	-40 to +150	$^{\circ}\!\mathbb{C}$
	R ө да	Junction to Ambient on printed circuit	90	°C/W

^{*} For surge ratings, see table below.

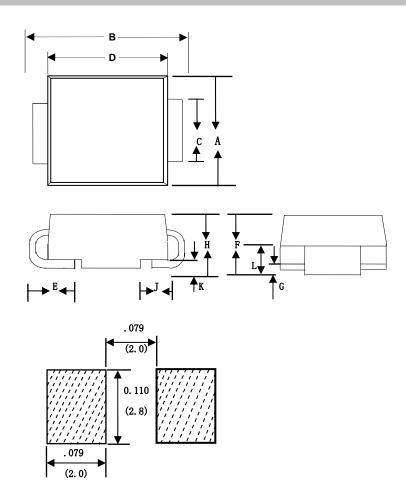


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Dimensions



Dimension	In	ches	Millimeters		
	MIN	MAX	MIN	MAX	
A	0. 134	0. 155	3. 40	3. 94	
В	0. 205	0. 22	5. 21	5. 59	
С	0. 075	0. 083	1. 90	2. 11	
D	0. 166	0. 185	4. 22	4. 70	
Е	0. 036	0. 056	0. 91	1. 42	
F	0. 073	0. 087	1. 85	2. 2	
G	0.002	0.008	0. 05	0. 20	
Н	0. 077	0.094	1. 95	2. 40	
J	0. 043	0. 053	1. 09	1. 35	
K	0.008	0.014	0. 20	0. 35	
L	0. 039	0. 049	0. 99	1.24	

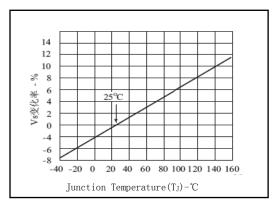


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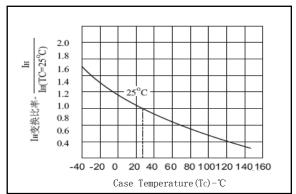
Summary of Packing Options

Package Type	Description	Packing Quantity	Industry Standard
DO-214AA	Embossed Carrier Reel Pack	2500 PCS	EIA-481-1

Thermal Derating Curves



Normalized VS Change versus Junction Temperature



Normalized DC Holding Current versus Case Temperature

